HEF4104B

Quad low-to-high voltage translator with 3-state outputs Rev. 10 — 14 December 2021 Product data sheet

1. General description

The HEF4104B is a quad low-to-high voltage translator with complementary 3-state outputs (Bn and $\overline{B}n$). A LOW on the output enable input (OE) causes the outputs to assume a high-impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{DD} .

2. Features and benefits

- Wide supply voltage range from 3.0 V to 15.0 V
- CMOS low power dissipation
- · High noise immunity
- · Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- · Complies with JEDEC standard JESD 13-B
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C

3. Ordering information

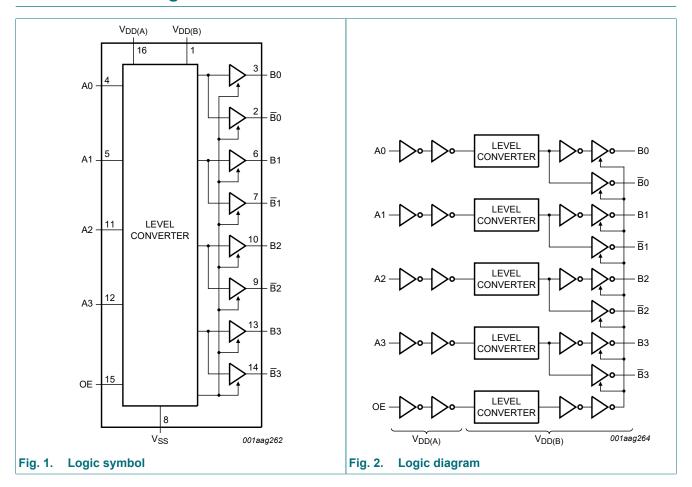
Table 1. Ordering information

Table 1. Ordering information							
Type number Package							
	Temperature range	Name	Description	Version			
HEF4104BT	-40 °C to +85 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			



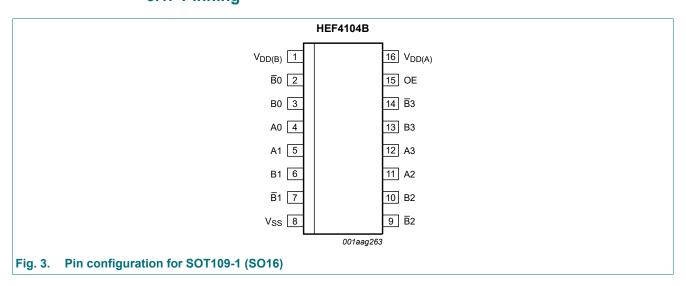
Quad low-to-high voltage translator with 3-state outputs

4. Functional diagram



5. Pinning information

5.1. Pinning



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5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{DD(B)}$	1	supply voltage port B
B0, B1, B2, B3	2, 7, 9, 14	complementary data output
B0, B1, B2, B3	3, 6, 10, 13	data output
A0, A1, A2, A3	4, 5, 11, 12	data input
V _{SS}	8	common negative supply voltage (0 V)
OE	15	output enable input
$V_{DD(A)}$	16	supply voltage port A

6. Functional description

Table 3. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; Z = high-impedance OFF-state.}$

Control	Output				
OE	Bn	Bn			
Н	An	Ān			
L	Z	Z			

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{\rm SS}$ = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD(A)}$	supply voltage A	port A; $V_{DD(A)} \le V_{DD(B)}$	-0.5	+18	V
$V_{DD(B)}$	supply voltage B	port B; $V_{DD(B)} \ge V_{DD(A)}$	-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD(A)} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD(A)} + 0.5$	V
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{DD(B)} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current	[1]	-	50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +85 °C	-	500	mW
Р	power dissipation	per output	-	100	mW

^[1] I_{DD} is the combined current of $I_{DD(A)}$ and $I_{DD(B)}$.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD(A)}$	supply voltage A		3	-	≤ V _{DD(B)}	V
$V_{DD(B)}$	supply voltage B		≥ V _{DD(A)}	-	15	V
VI	input voltage		0	-	$V_{DD(A)}$	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{DD(A)} = 5 V	-	-	3.75	μs/V
		V _{DD(A)} = 10 V	-	-	0.5	μs/V
		V _{DD(A)} = 15 V	-	-	0.08	μs/V

9. Static characteristics

Table 6. Static characteristics

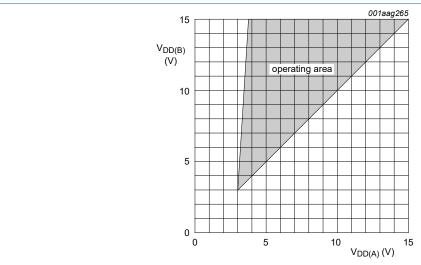
 $V_{DD(A)} = V_{DD(B)}$; $V_{SS} = 0$ V; $V_I = V_{SS}$ or $V_{DD(A)}$; unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD} [1]	T _{amb} =	-40 °C	T _{amb} =	+25 °C	T _{amb} =	+85 °C	Unit
				Min	Max	Min	Max	Min	Max	V V V V V V V V V V W MA
V _{IH}	HIGH-level input	I _O < 1 µA	5 V	3.5	-	3.5	-	3.5	-	V
	voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V _{IL}	LOW-level input voltage	I _O < 1 μΑ	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level output	I _O < 1 μΑ	5 V	4.95	-	4.95	-	4.95	-	V
	voltage		10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL}	LOW-level output	I _O < 1 μΑ	5 V	-	0.05	-	0.05	-	0.05 V 0.05 V	
	voltage		10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output	V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
	current	V _O = 4.6 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level output	V _O = 0.4 V	5 V	0.52	-	0.44	-	0.36	-	mA
	current	V _O = 0.5 V	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
I _I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μA
I _{DD}	supply current	all valid input	5 V [2]	-	20	-	20	-	150	μA
		combinations;	10 V	-	40	-	40	-	300	μA
		I _O = 0 A	15 V	-	80	-	80	-	600	μA
l _{OZ}	OFF-state output	HIGH; $V_O = V_{DD(B)}$	15 V	-	1.6	-	1.6	-	12.0	μA
	current	LOW; V _O = V _{SS}	15 V	-	-1.6	-	-1.6	-	-12.0	μΑ

Quad low-to-high voltage translator with 3-state outputs

Symbol	Parameter	Conditions	V _{DD} [1]	T _{amb} =	T _{amb} = -40 °C		T _{amb} = +25 °C T _{amb} = +85 °C		+85 °C	Unit
				Min	Max	Min	Max	Min	Max	
C _I	input capacitance	digital inputs	-	-	-	-	7.5	-	-	pF

- V_{DD} is the same as $V_{DD(A)}$ and $V_{DD(B)}.$ I_{DD} is the combined current of $I_{DD(A)}$ and $I_{DD(B)}.$



The shaded area shows the permissible operating range.

 $V_{\text{DD(B)}}$ as a function of $V_{\text{DD(A)}}$

10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = 25 °C unless otherwise specified; for test circuit see <u>Fig. 7</u>.

Symbol	Parameter	Conditions	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	An to Bn, Bn; see Fig. 5					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	143 ns + (0.55 ns/pF)C _L	-	170	340	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	69 ns + (0.23 ns/pF)C _L	-	80	160	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	57 ns + (0.16 ns/pF)C _L	-	65	135	ns
t _{PLH}	LOW to HIGH	An to Bn, Bn; see Fig. 5					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	143 ns + (0.55 ns/pF)C _L	-	170	340	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	69 ns + (0.23 ns/pF)C _L	-	80	160	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	62 ns + (0.16 ns/pF)C _L	-	70	140	ns
t _{THL}	HIGH to LOW output	Bn or Bn; see Fig. 6					
	transition time	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _{TLH}	LOW to HIGH output	Bn or Bn; see Fig. 6					
	transition time	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	10 ns + (1.00 ns/pF)C _L	-	60	340 n 160 n 135 n 340 n 160 n 140 n 120 n 60 n 120 n 60 n	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	6 ns + (0.28 ns/pF)C _L	-	20	40	ns

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Quad low-to-high voltage translator with 3-state outputs

Symbol	Parameter	Conditions	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PHZ}	HIGH to OFF-state	OE to Bn, Bn; see Fig. 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	70	135	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	55	110	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	60	120	ns
t _{PLZ} LOW to OFF-state	OE to Bn, Bn; see Fig. 6						
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	70	135	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	55	105	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	55	110	ns
t _{PZH}	OFF-state to HIGH	OE to Bn, Bn; see Fig. 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	195	395	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	95	195	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	80	165	ns
t _{PZL}	OFF-state to LOW	OE to Bn, Bn; see Fig. 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	195	395	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	95	190	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	80	160	ns

^[1] Typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C_L in pF).

Table 8. Dynamic power dissipation

 $V_{DD(A)}=V_{DD(B)};~V_{SS}=0~V;~t_r=t_f\leq 20~ns;~T_{amb}=25~^{\circ}\mathrm{C}.$

Symbol	Parameter	V _{DD} [1]	Typical formula (μW)	where
P_D	dynamic power	5 V	$P_{D} = 3000 \times f_{i} + \Sigma (f_{o} \times C_{L}) \times V_{DD}^{2}$	f _i = input frequency in MHz;
	dissipation	10 V	$P_D = 12200 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _o = output frequency in MHz; C _I = output load capacitance in pF;
		15 V		Σ (f _o × C _L) = sum of the outputs; V_{DD} = supply voltage in V.

^[1] V_{DD} is the same as $V_{DD(A)}$ and $V_{DD(B)}$.

Quad low-to-high voltage translator with 3-state outputs

10.1. Waveforms and test circuit

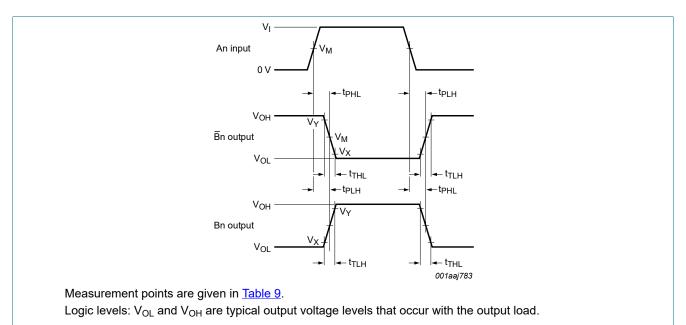


Fig. 5. Data input (An) to data output (Bn, Bn) propagation delays and output transition times

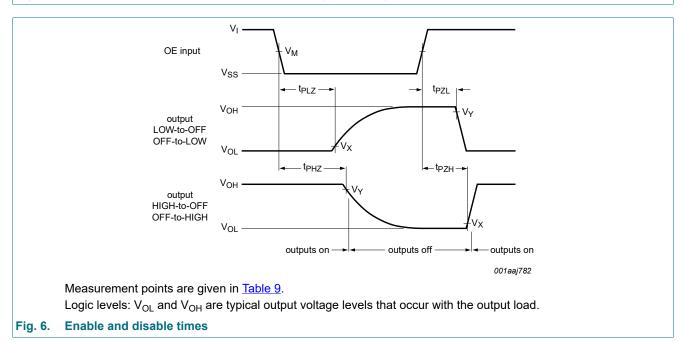
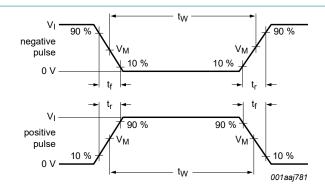


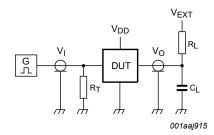
Table 9. Measurement points

Input		Output		
V _I	V _M	V _M	V _X	V _Y
V _{SS} or V _{DD(A)}	0.5V _{DD(A)}	$0.5V_{DD(B)}$	0.1V _{DD(B)}	0.9V _{DD(B)}

Quad low-to-high voltage translator with 3-state outputs



a. Input waveforms



b. Test circuit

Test data given in Table 10.

Definitions for test circuit:

 C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator

Fig. 7. Test circuit for measuring switching times

Table 10. Test data

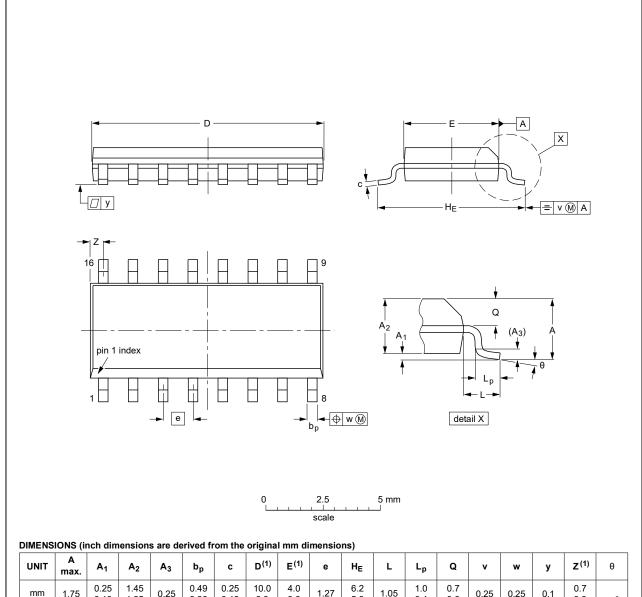
Supplies	Input	Load		V _{EXT}		
$V_{DD(A)} = V_{DD(B)}$	t _r , t _f	R_L	C_L t_{PHL}, t_{PLH} t_{PZL}, t_{PLZ} t_{P}			t _{PZH} , t _{PHZ}
5 V to 15 V	≤ 20 ns	1 kΩ	50 pF	open	$V_{DD(B)}$	V_{SS}

Quad low-to-high voltage translator with 3-state outputs

11. Package outline



SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig. 8. Package outline SOT109-1 (SO16)

Quad low-to-high voltage translator with 3-state outputs

12. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

13. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
HEF4104B v.10	20211214	Product data sheet	-	HEF4104B v.8			
Modifications:	Nexperia. • Legal texts ha	this data sheet has been redes ve been adapted to the new co Section 2 updated. ded.					
HEF4104B v.9	20160329	Product data sheet	-	HEF4104B v.8			
Modifications:	Type number	HEF4104BP (SOT38-4) remov	ed.				
HEF4104B v.8	20111111	Product data sheet	-	HEF4104B v.7			
Modifications:	 Section Applications removed Table 6: I_{OH} minimum values changed to maximum 						
HEF4104B v.7	20091216	Product data sheet	-	HEF4104B v.6			
HEF4104B v.6	20091102	Product data sheet	-	HEF4104B v.5			
HEF4104B v.5	20090728	Product data sheet	-	HEF4104B v.4			
HEF4104B v.4	20090305	Product data sheet	-	HEF4104B_CNV v.3			
HEF4104B_CNV v.3	19950101	Product specification	-	HEF4104B_CNV v.2			
HEF4104B_CNV v.2	19950101	Product specification	-	-			

Quad low-to-high voltage translator with 3-state outputs

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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